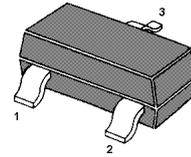
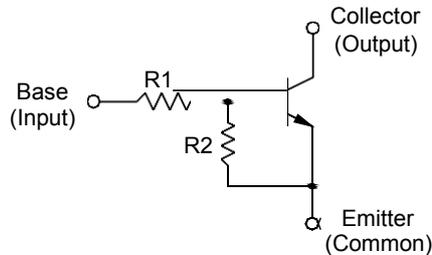


NPN Silicon Epitaxial Planar Transistor

for switching and interface circuit and drive circuit applications



1.Base 2.Emitter 3.Collector
SOT-23 Plastic Package

Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

Resistor Values

Type	Marking	R1 (KΩ)	R2 (KΩ)
MMBTRC101SS	NA	4.7	4.7
MMBTRC102SS	NB	10	10
MMBTRC103SS	NC	22	22
MMBTRC104SS	ND	47	47
MMBTRC105SS	NF	2.2	47
MMBTRC106SS	NE	4.7	47

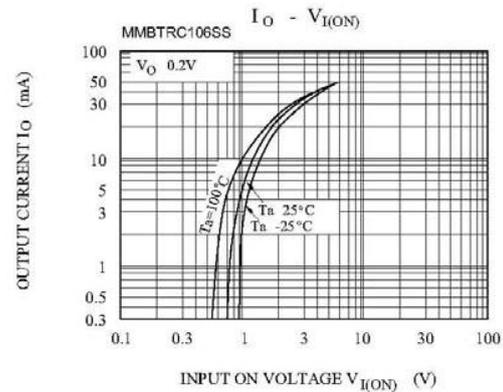
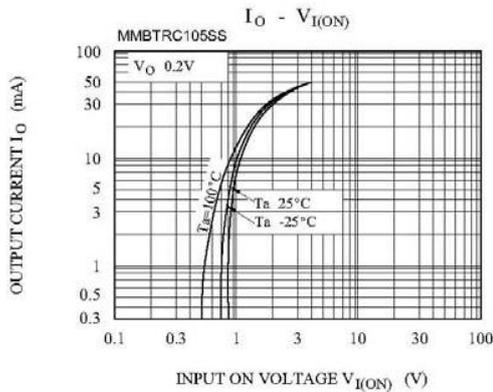
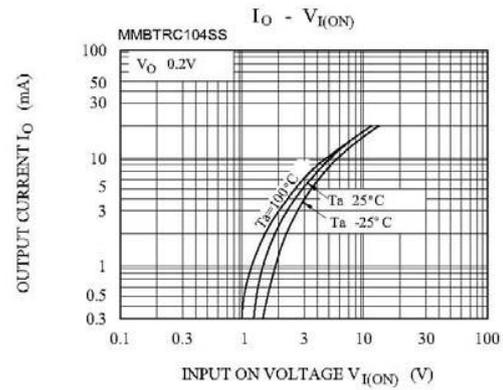
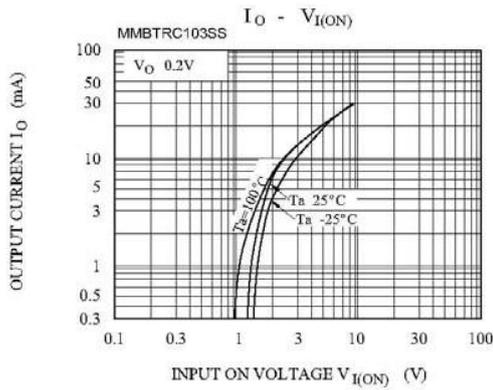
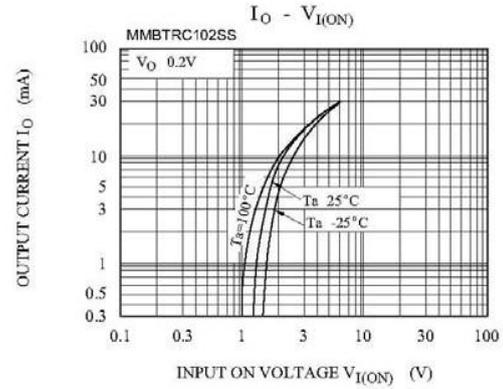
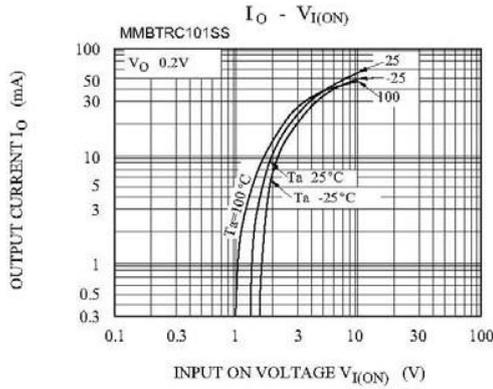
Absolute Maximum Ratings (T_a = 25 °C)

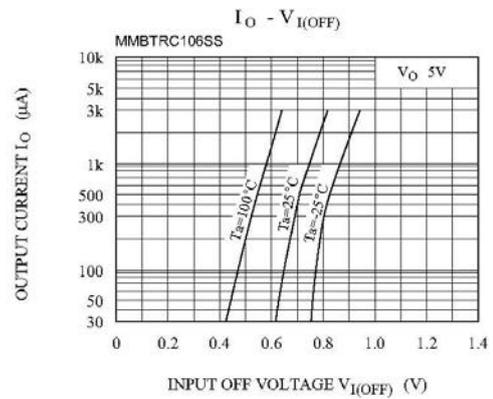
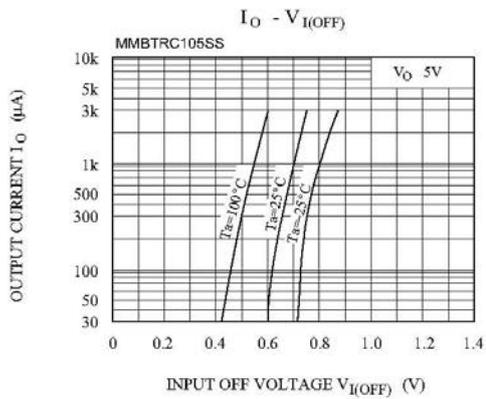
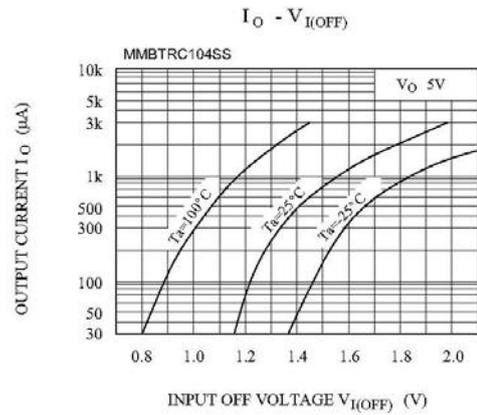
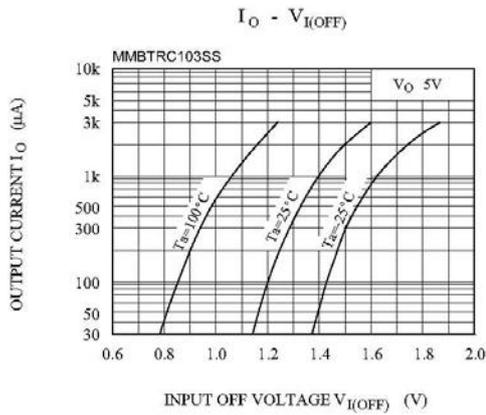
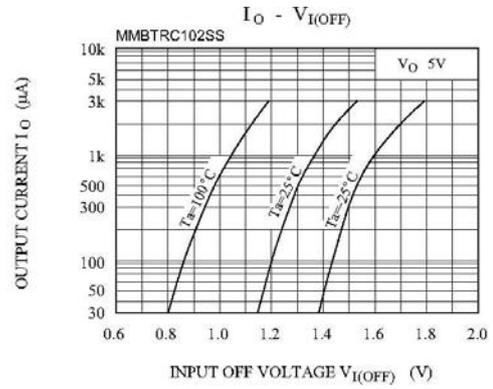
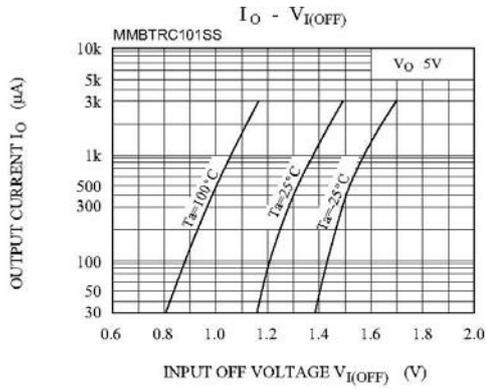
Parameter		Symbol	Value	Unit
Output Voltage		V _O	50	V
Input Voltage	MMBTRC101SS	V _I	20, -10	V
	MMBTRC102SS		30, -10	
	MMBTRC103SS		40, -10	
	MMBTRC104SS		40, -10	
	MMBTRC105SS		12, -5	
	MMBTRC106SS		20, -5	
Output Current		I _O	100	mA
Total Power Dissipation		P _{tot}	200	mW
Junction Temperature		T _j	150	°C
Storage Temperature Range		T _{stg}	- 55 to + 150	°C

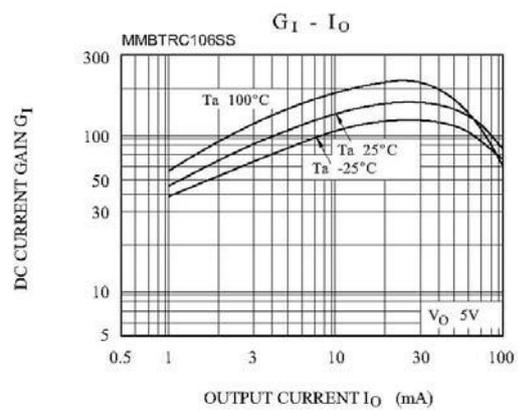
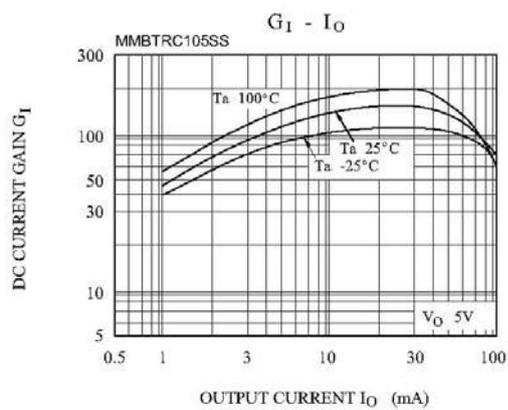
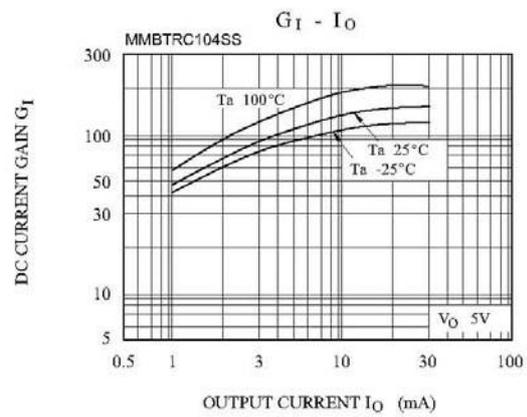
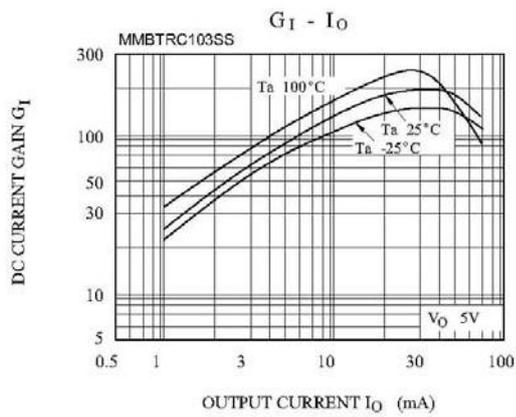
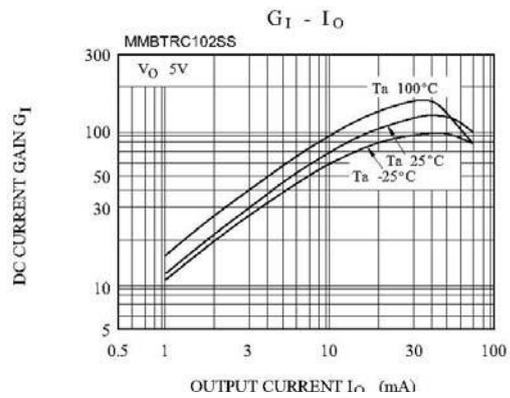
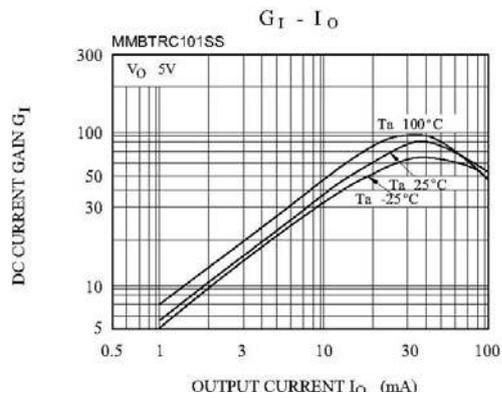
Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	
DC Current Gain at $V_o = 5\text{ V}$, $I_o = 10\text{ mA}$	MMBTRC101SS MMBTRC102SS MMBTRC103SS MMBTRC104SS MMBTRC105SS MMBTRC106SS	G_i	30 50 70 80 80 80	- - - - - -	- - - - - -	- - - - - -
Output Cutoff Current at $V_o = 50\text{ V}$		$I_{O(OFF)}$	-	-	500	nA
Input Current at $V_i = 5\text{ V}$	MMBTRC101SS MMBTRC102SS MMBTRC103SS MMBTRC104SS MMBTRC105SS MMBTRC106SS	I_i	- - - - - -	- - - - - -	1.8 0.88 0.36 0.18 3.6 1.8	mA
Output Voltage at $I_o = 10\text{ mA}$, $I_i = 0.5\text{ mA}$		$V_{O(ON)}$	-	-	0.3	V
Input Voltage (ON) at $V_o = 0.2\text{ V}$, $I_o = 5\text{ mA}$	MMBTRC101SS MMBTRC102SS MMBTRC103SS MMBTRC104SS MMBTRC105SS MMBTRC106SS	$V_{I(ON)}$	- - - - - -	- - - - - -	2 2.4 3 5 1.1 1.3	V
Input Voltage (OFF) at $V_o = 5\text{ V}$, $I_o = 0.1\text{ mA}$	MMBTRC101SS~104SS MMBTRC105SS~106SS	$V_{I(OFF)}$	1 0.5	- -	- -	V
Transition Frequency at $V_o = 10\text{ V}$, $I_o = 5\text{ mA}$		f_T ¹⁾	-	200	-	MHz

1) Characteristic of transistor only.







Pc-Ta

